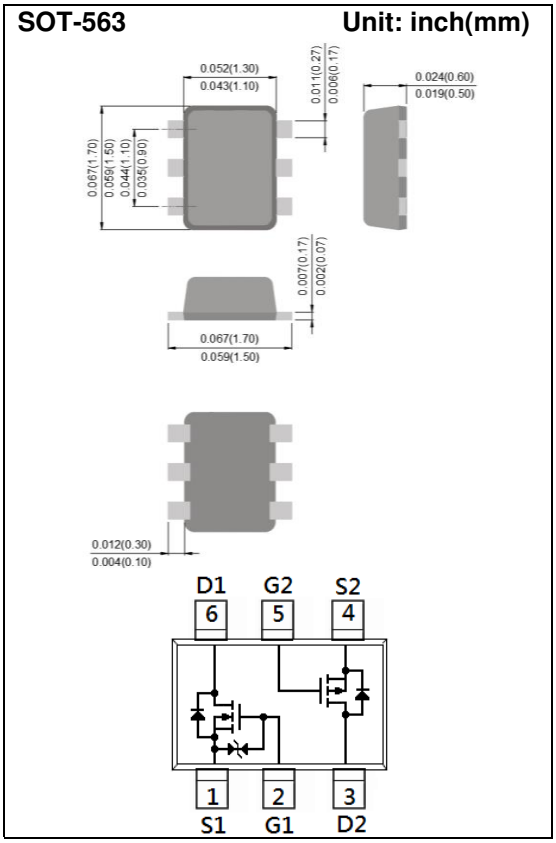
PJX8603

Complementary Enhancement Mode MOSFET – ESD Protected

Voltage	50 / -60V	Current	0.36A / -0.2A

SOT-563 Unit: inch(mm)



Features

- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : SOT-563 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0026 grams
- Marking : X63

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	N-Ch LIMIT	P-Ch LIMIT	UNITS
Drain-Source Voltage		V_{DS}	50	-60	V
Gate-Source Voltage		V_{GS}	±20	±20	V
Continuous Drain Current		I_D	360	-200	mA
Pulsed Drain Current(Note 4)		I_{DM}	1200	-900	mA
Power Dissipation	T_a=25°C	P_D	300		mW
	Derate above 25°C		2.4		mW/°C
Operating Junction and Storage Temperature Range		T_J,T_{STG}	-55~150		°C
Typical Thermal Resistance - Junction to Ambient(Note 3)		$R_{\theta JA}$	417		°C/W

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N-Channel Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V, I_D= 250uA	50	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D= 250uA	0.5	0.9	1.0	V
Drain-Source On-State Resistance	$R_{DS(on)}$	V_{GS}= 10V, I_D= 500mA	-	1.26	1.5	Ω
		V_{GS}= 4.5V, I_D= 200mA	-	1.34	2.5	
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}= 50V, V_{GS}=0V	-	-	1	uA
Gate-Source Leakage Current	I_{GSS}	V_{GS}=±20V, V_{DS}=0V	-	-	±10	uA
Dynamic(Note 5)						
Total Gate Charge	Q_g	V_{DS}=25V, I_D=500mA, V_{GS}=4.5V	-	0.95	-	nC
Gate-Source Charge	Q_{gs}		-	0.34	-	
Gate-Drain Charge	Q_{gd}		-	0.32	-	
Input Capacitance	Ciss	V_{DS}=25V, V_{GS}=0V, f=1.0MHZ	-	36	-	pF
Output Capacitance	Coss		-	11	-	
Reverse Transfer Capacitance	Crss		-	6.6	-	
Turn-On Delay Time	$td_{(on)}$	V_{DD}=25V, I_D=500mA, V_{GS}=10V, R_G=6Ω(Note 1,2)	-	2.3	-	ns
Turn-On Rise Time	tr		-	20	-	
Turn-Off Delay Time	$td_{(off)}$		-	7	-	
Turn-Off Fall Time	tf		-	20	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	360	mA
Diode Forward Voltage	V_{SD}	I_S= 500mA, V_{GS}=0V	-	0.9	1.5	V

NOTES :

1. Pulse width≤300us, Duty cycle≤2%
2. Essentially independent of operating temperature typical characteristics.
3. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.

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P-Channel Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V,I_D=-250uA	-60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=-250uA	-1.0	-1.5	-2.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	V_{GS}=-10V,I_D=-500mA	-	2.6	6	Ω
		V_{GS}=-4.5V,I_D=-200mA	-	2.9	7	
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=-48V,V_{GS}=0V	-	-	-1	uA
Gate-Source Leakage Current	I_{GSS}	V_{GS}=±20V,V_{DS}=0V	-	-	±100	nA
Dynamic(Note 5)						
Total Gate Charge	Q_g	V_{DS}=-25V, I_D=-100mA, V_{GS}=-4.5V	-	1.1	-	nC
Gate-Source Charge	Q_{gs}		-	0.3	-	
Gate-Drain Charge	Q_{gd}		-	0.2	-	
Input Capacitance	Ciss	V_{DS}=-25V, V_{GS}=0V, f=1.0MHZ	-	51	-	pF
Output Capacitance	Coss		-	15	-	
Reverse Transfer Capacitance	Crss		-	2.2	-	
Turn-On Delay Time	$td_{(on)}$	V_{DD}=-25V, I_D=-100mA, V_{GS}=-10V, R_G=6Ω(Note 1,2)	-	4.8	-	ns
Turn-On Rise Time	tr		-	19	-	
Turn-Off Delay Time	$td_{(off)}$		-	52	-	
Turn-Off Fall Time	tf		-	32	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	-200	mA
Diode Forward Voltage	V_{SD}	I_S=-500mA, V_{GS}=0V	-	-0.9	-1.5	V

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N-Channel TYPICAL CHARACTERISTIC CURVES

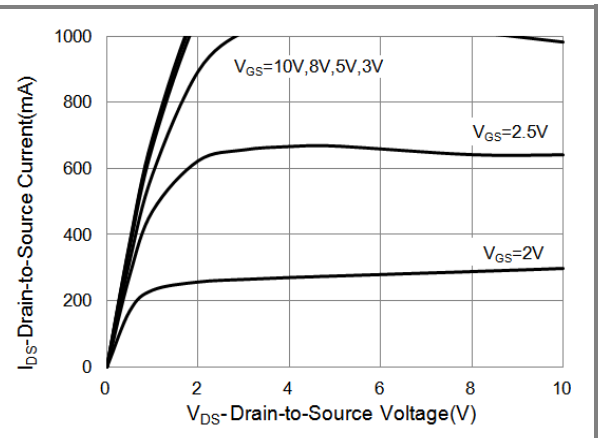

Fig.1 On-Region Characteristics

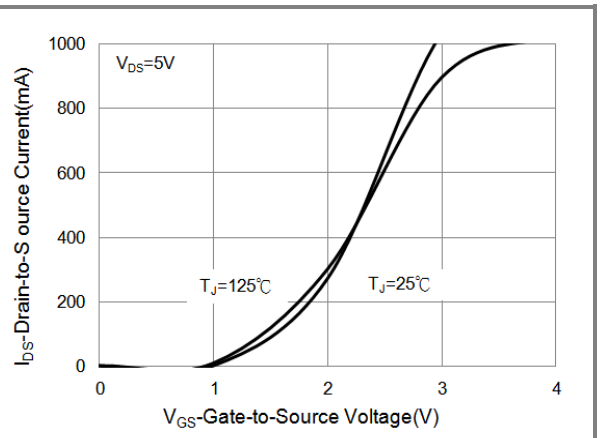

Fig.2 Transfer Characteristics

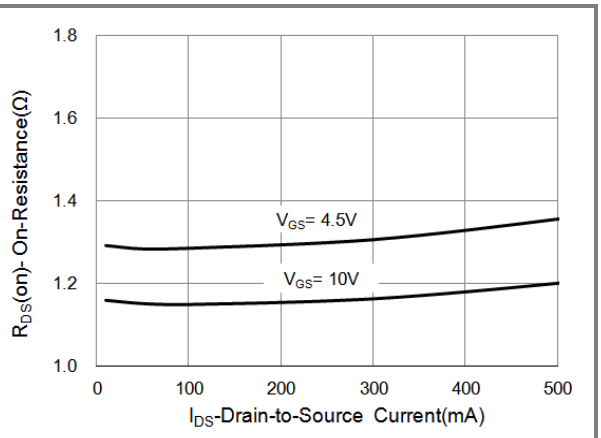

Fig.3 On-Resistance vs. Drain Current

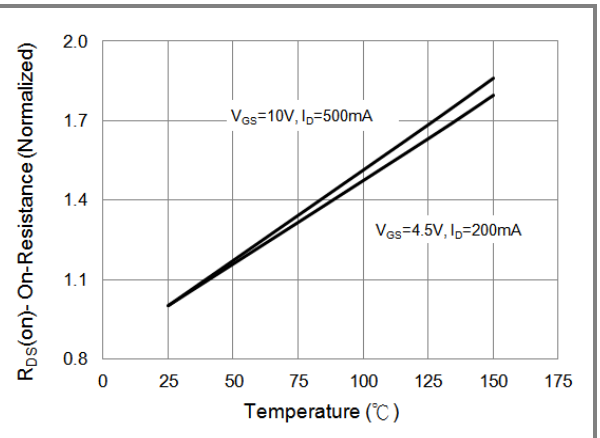

Fig.4 On-Resistance vs. Junction temperature

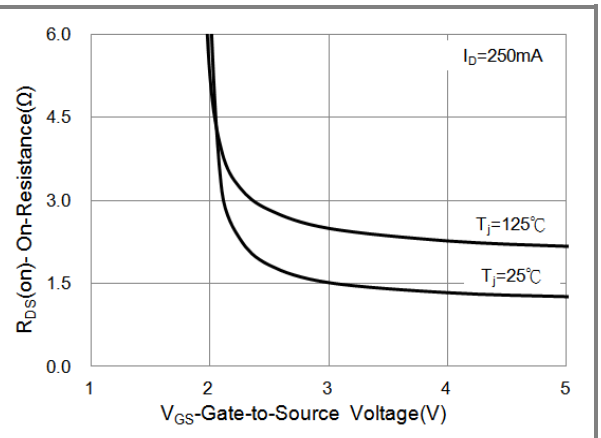

Fig.5 On-Resistance Variation with VGS.

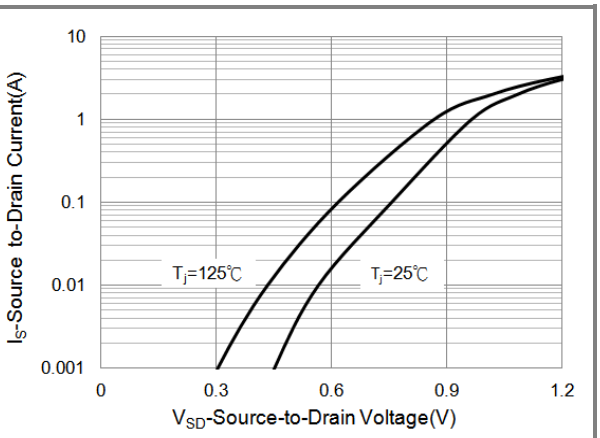

Fig.6 Body Diode Characteristics

N-Channel TYPICAL CHARACTERISTIC CURVES

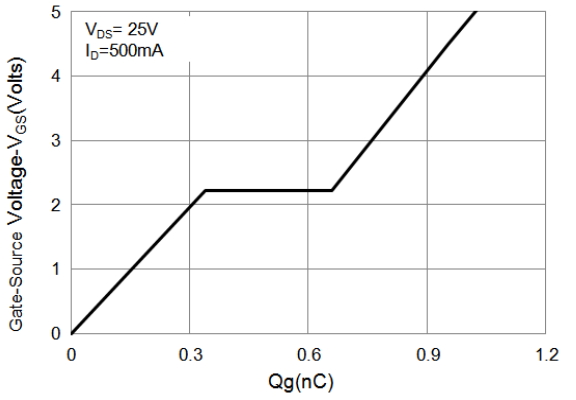

Fig.7 Gate-Charge Characteristics

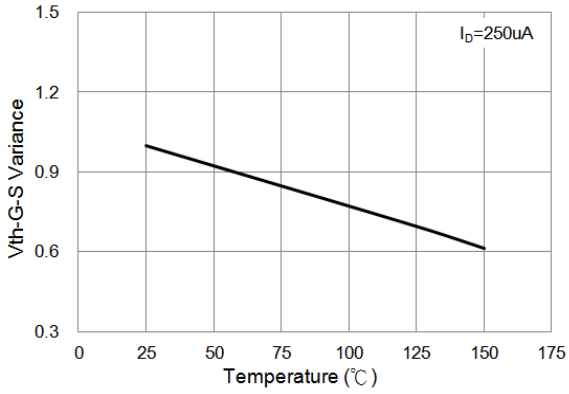

Fig.8 Threshold Voltage Variation with Temperature.

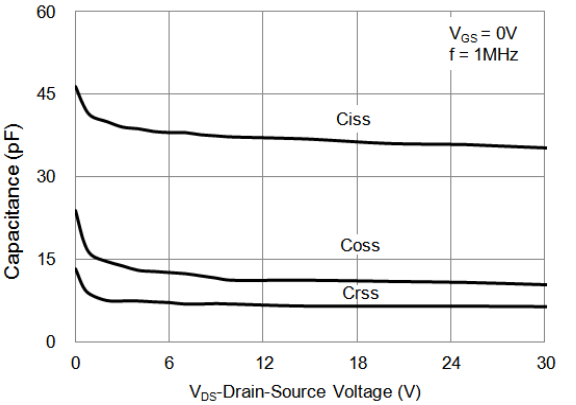

Fig.9 Capacitance vs. Drain-Source Voltage.

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P-Channel TYPICAL CHARACTERISTIC CURVES

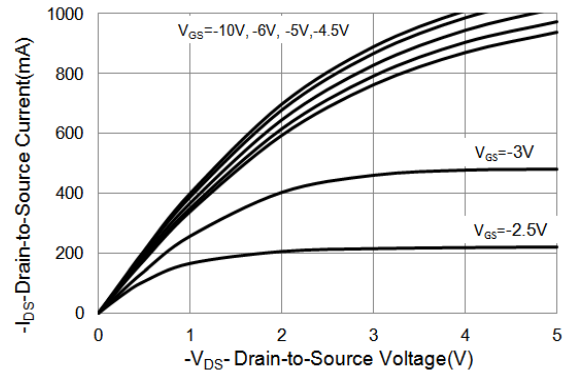

Fig.1 On-Region Characteristics

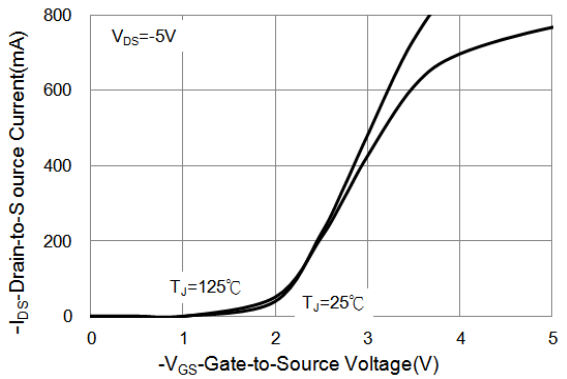

Fig.2 Transfer Characteristics

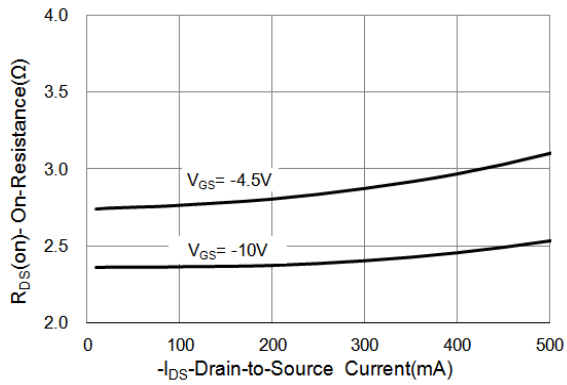

Fig.3 On-Resistance vs. Drain Current

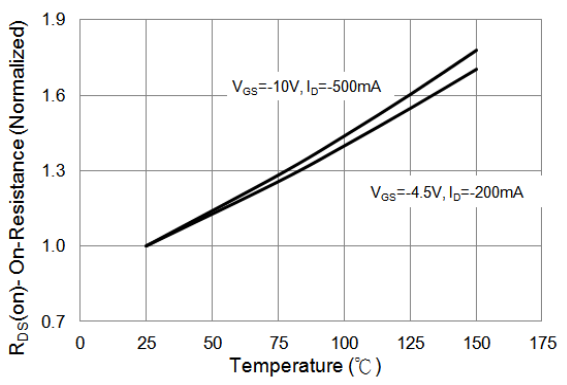

Fig.4 On-Resistance vs. Junction temperature

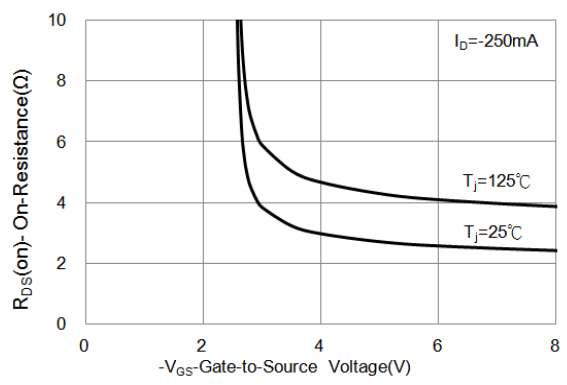

Fig.5 On-Resistance Variation with VGS.

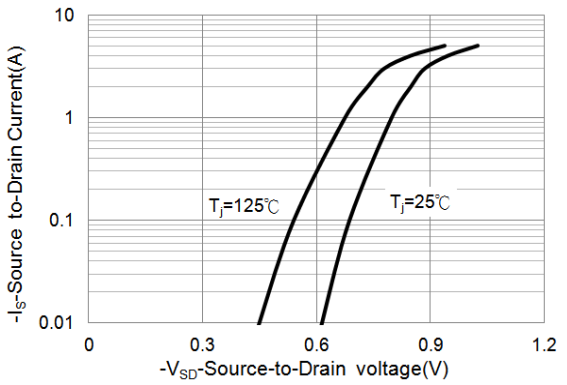

Fig.6 Body Diode Characteristics

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P-Channel TYPICAL CHARACTERISTIC CURVES

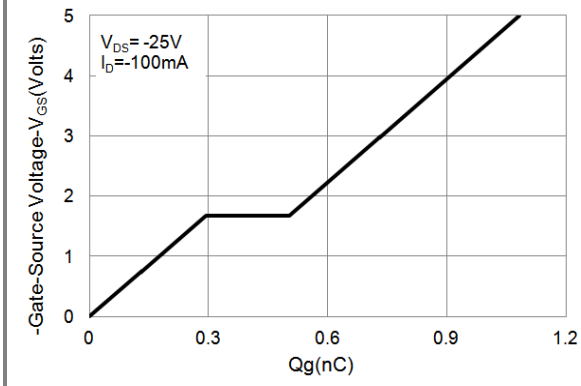


Fig.7 Gate-Charge Characteristics

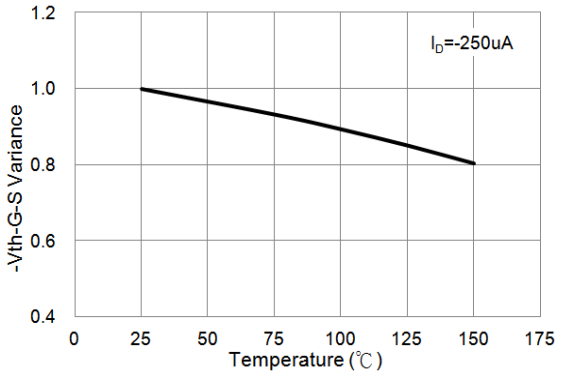


Fig.8 Threshold Voltage Variation with Temperature.

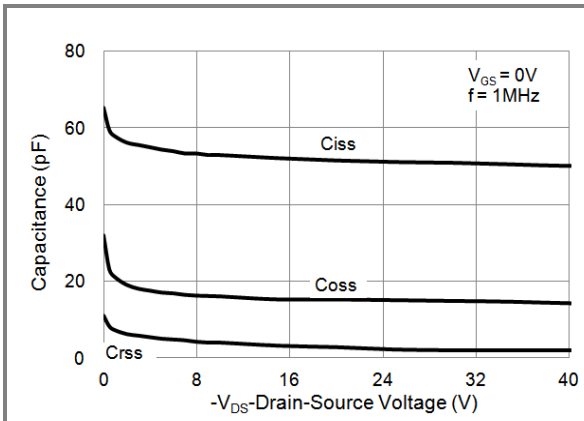


Fig.9 Threshold Voltage Variation with Temperature.

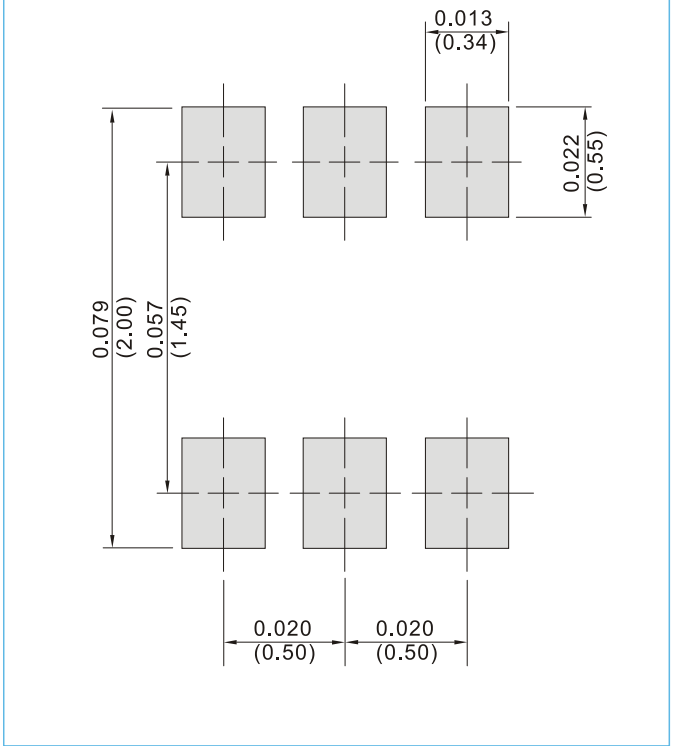
PJX8603

PART NO. PACKING CODE VERSION

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJX8603_R1_00001	SOT-563	4K pcs / 7” reel	X63	Halogen free RoHS compliant
PJX8603_R2_00001	SOT-563	10K pcs / 13” reel	X63	Halogen free RoHS compliant
PJX8603_R1_00002	SOT-563	8K pcs / 7” reel	X63	Halogen free RoHS compliant
PJX8603_R2_00002	SOT-563	20K pcs / 13” reel	X63	Halogen free RoHS compliant

MOUNTING PAD LAYOUT

SOT-563 Unit : inch(mm)



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